NSN 5962-01-413-5392

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View Online at https://aerobasegroup.com/nsn/5962-01-413-5392

Body Length:

- 1.490 inches
- **Body Width:**

0.610 inches

Body Height:

0.232 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+150.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

F-16

Features Provided:

Burn in and electrostatic sensitive and erasable and monolithic and positive outputs and tested to mil-std-883

Inclosure Material:

Ceramic

Inclosure Configuration:

Quad-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Case Outline Source And Designator:

D-10 mil-m-38510

Terminal Surface Treatment:

Solder

Product Name:

Microcircuits digital, cmos 8k x 8 bit eeprom, monolithic silicon

Voltage Rating And Type Per Characteristic:

0.3 volts total supply and 6.25 volts total supply

Time Rating Per Chacteristic:

250.00 nanoseconds access

Memory Device Type:

Eeprom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A458a0

